2022년 1월 26일(수), 10:45-12:30 Room J (하트 III, 6층)

H. Display and Imaging Technologies 분과 [WJ2-H] Display Technology I

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작성: 국신성 포구(인상내역포), 임유승 포구(제송내역포 	
WJ2-H-1 10:45-11:15	Development of Digital Transformation in the Display Industry Ilho Kim, Seokwoo Lee, and Sooyoung Yoon LG Display Co., Ltd.
WJ2-H-2 11:15-11:30	Improvement in Device Performance of Trench-Structured Vertical Thin Film Transistors with IGZO Bilayer Channel Configuration Prepared by ALD Soo Hyun Bae ¹ , Jong-Heon Yang ² , Yong-Hae Kim ² , Chi-Sun Hwang ² , Young Ha Kwon ³ , Nak-Jin-Seong ³ , Kyu-Jeong Choi ³ , and Sung Min Yoon ¹ 1Kyung Hee University, 2ETRI, 3NCD Co., Ltd.
WJ2-H-3 11:30-11:45	Bending Stability Analysis of Flexible Oxide Thin Film Transistor with iCVD-Based Organic Layer Tae-Seung Jung and Sang-Hun Jeon School of Electrical Engineering, KAIST
WJ2-H-4 11:45-12:00	Plasma-enhanced Atomic Layer Deposited Indium Oxide Film Using a New Novel Liquid DMION Indium Precursor for Thin Film Transistors Su-Hwan Choi ¹ , Tae Hyun Hong ² , Seong-Hwan Ryu ² , Jeong Hun Kim ³ , Hyun Kyung Lee ³ , Jang Hyeon Seok ³ , Jung Woo Park ³ , and Jin-seong Park ^{1,2} ¹ Division of Nanoscale of Semiconductor Engineering, Hanyang University, ² Divison of Materials Science and Engineering, Hanyang University, ³ Thin Film Materials Team, Hansol Chemical
WJ2-H-5 12:00-12:15	Effects of Proton Beam Irradiation on the Active Layer Thickness of IGTO Thin Film Transistor Min-Gyu Shin, Seong-Hyun Hwang, Kie Yatsu, Dong-Ho Lee, and Hyuck-In Kwon School of Electrical and Electronics Engineering, Chung-Ang University
WJ2-H-6 12:15-12:30	Impact of Device Geometry for Improving the Device Performance of Mesa-Shaped Vertical-Channel Thin-Film Transistors Using ALD-IGZO Channel Hyun-Min Ahn ¹ , Soo Hyun Bae ¹ , Young-Ha Kwon ² , Nak-Jin Seong ² , Kyu-Jeong Choi ² , Jong-Heon Yang ³ , Yong-Hae Kim ³ , Chi-Sun Hwang ³ , and Sung-Min Yoon ¹ **IKyung Hee University, **2NCD, **3ETRI**